

Elastic Strain and Stress by Rietveld Method

Davor Balzar^{1,2} and Hassel Ledbetter¹

¹ Materials Science and Engineering Laboratory
National Institute of Standards and Technology

² Physics Department
University of Colorado
Boulder, Colorado

ECM-18

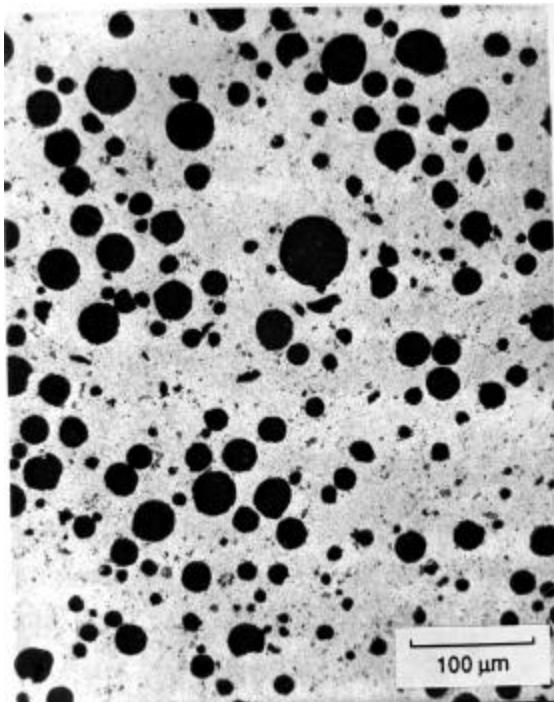
Praha

August 19, 1998



Why Rietveld refinement ?

Al/Mullite-Alumina Composites



- Al-6061 matrix

STRONG TEXTURE

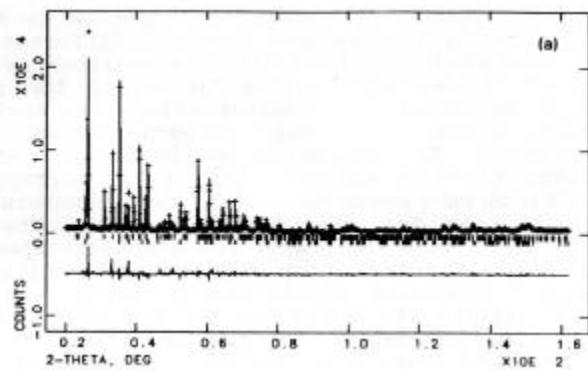
- α -alumina

STRESS ?

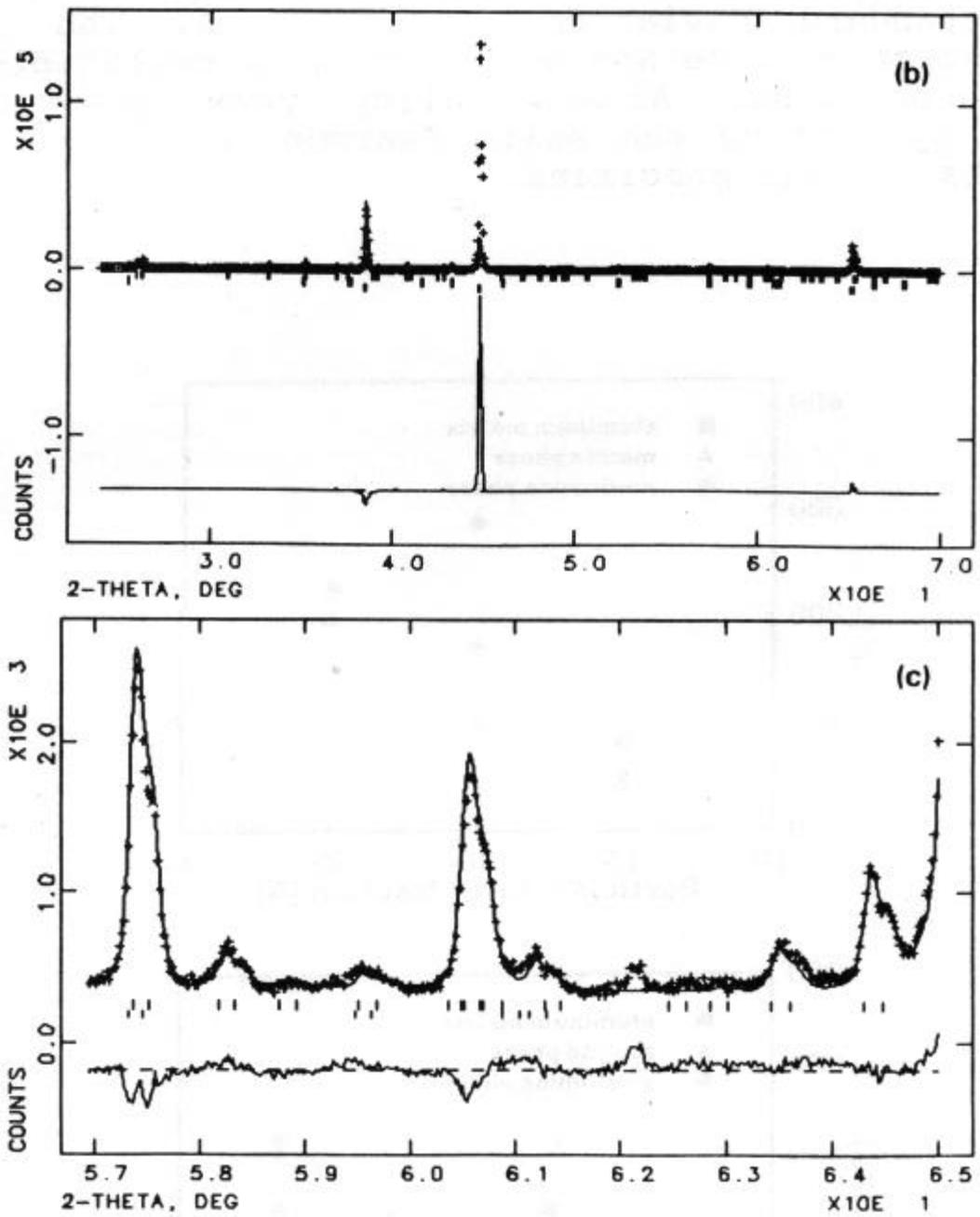
- Mullite

- ▶ $\text{Al}_2(\text{Al}_{2+2x}\text{Si}_{2-2x})\text{O}_{10-x}$
- ▶ $Pbam$ ($a \approx b \approx 7.6 \text{ \AA}$,
 $c \approx 2.9 \text{ \AA}$)
- ▶ Incommensurate
modulation

STRESS ?



X-Ray Diffraction



Consequences

- Complete diffraction pattern
 - ▶ All available hkl s TEXTURE !
- Texture determination by Rietveld (GSAS)
 - ▶ Low symmetries
 - ▶ Multiphase mixtures
 - ▶ Residual stress
- Data collection
 - ▶ Monochromatic sources
 - Position-sensitive detectors
 - Section of the pattern
 - ▶ Polychromatic sources
 - Neutron TOF
 - EDXRD

Stress by diffraction

- Diffraction → STRAIN



$$\sigma_{ij} = C_{ijkl} e_{kl}$$

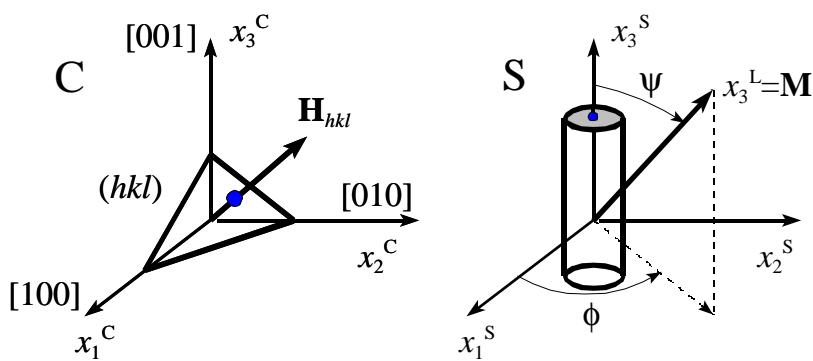
- Rietveld-refinement coding

$$\Delta T_h = (T - T_h) - \epsilon_{h,i} d - \epsilon_{h,a} d \Gamma$$

$$\Gamma_C = \beta_1^2 \beta_2^2 + \beta_2^2 \beta_3^2 + \beta_3^2 \beta_1^2 = \frac{h^2 k^2 + k^2 l^2 + l^2 h^2}{(h^2 + k^2 + l^2)^2}$$

$$\Gamma_H = \beta_3^2 = \frac{l^2}{\frac{4}{3} \frac{c^2}{a^2} (h^2 + hk + k^2) + l^2}$$

Strain measurements



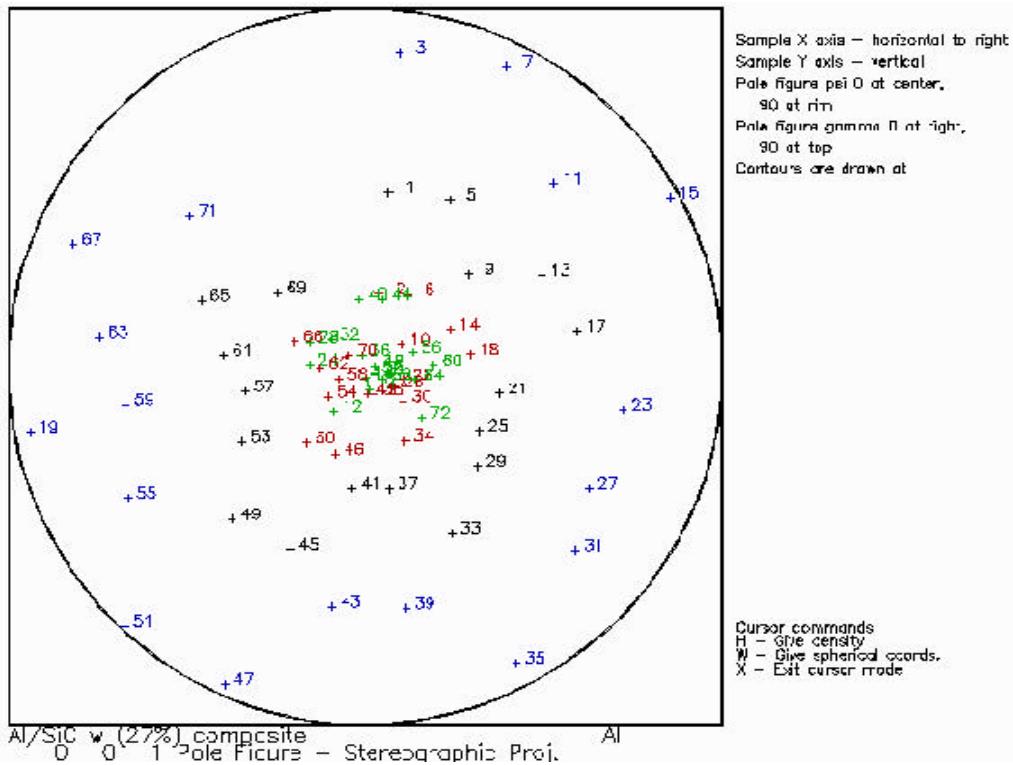
$$\mathbf{x}^L_i = \gamma_{ij} \mathbf{x}^S_j, \quad \gamma_{ij} = \Psi_{ik} \phi_{kj} = \begin{pmatrix} \cos\phi \cos\psi & \sin\phi \cos\psi & -\sin\psi \\ -\sin\phi & \cos\phi & 0 \\ \cos\phi \sin\psi & \sin\phi \sin\psi & \cos\psi \end{pmatrix}; \quad \mathbf{H}_{hkl} \parallel x_3^L.$$

$$e_{33}^L \equiv e_{\psi\phi} = d_{\psi\phi} / d_0 - 1$$

$$\begin{aligned} e_{\psi\phi} = e_{33} + & [e_{11} \cos^2\phi + e_{12} \sin 2\phi + e_{22} \sin^2\phi - e_{33}] \sin^2\psi \\ & + [e_{13} \cos\phi + e_{23} \sin\phi] \sin 2\psi \end{aligned}$$

6 unknowns: over-determined system, least-squares

Neutron TOF measurements LANSCE (Los Alamos)



- Texture and strain from the same data:
 - ▶ 13-18 specimen orientations
 - ▶ 4 patterns / orientation 52-72 patterns
 - ▶ Rietveld refinement:
 - > 250,000 data points !
 - > 1,800 refinable parameters !

Strain by Rietveld refinement

- Strain determined from:

- ▶ Particular d_{hkl}
- ▶ Lattice parameters from Rietveld refinement:

$$\langle d \rangle = \frac{1}{4\pi} \int_0^{\pi} d\psi \sin\psi \int_0^{2\pi} d\phi \ d_{\psi\phi}$$
$$d_{\psi\phi} = \frac{\int_0^{2\pi} d\omega \ d_{33}^L f(g)}{\int_0^{2\pi} d\omega f(g)}; \quad f(g) = \frac{dV/V}{dg}$$

- Quasi-isotropy:

$$\langle e \rangle \equiv \langle d \rangle / d_0 - 1 = (e_{11} + e_{22} + e_{33}) / 3$$

Strain

- Hydrostatic and deviatoric components:

$$e_{ij} = e'_{ij} + \delta_{ij} e^H$$

$$e_{\psi\phi} = \gamma_{3k} \gamma_{3l} e_{kl} = e^H + \gamma_{3k} \gamma_{3l} e'_{kl}$$

- Two possibilities:

- Lattice parameters refined (d_0 known):

$$\langle e \rangle \equiv e^H = (e_{11} + e_{22} + e_{33})/3$$

$$\epsilon_{h,i} \Rightarrow e'_{kl} \quad \text{no need for } d_0 (!)$$

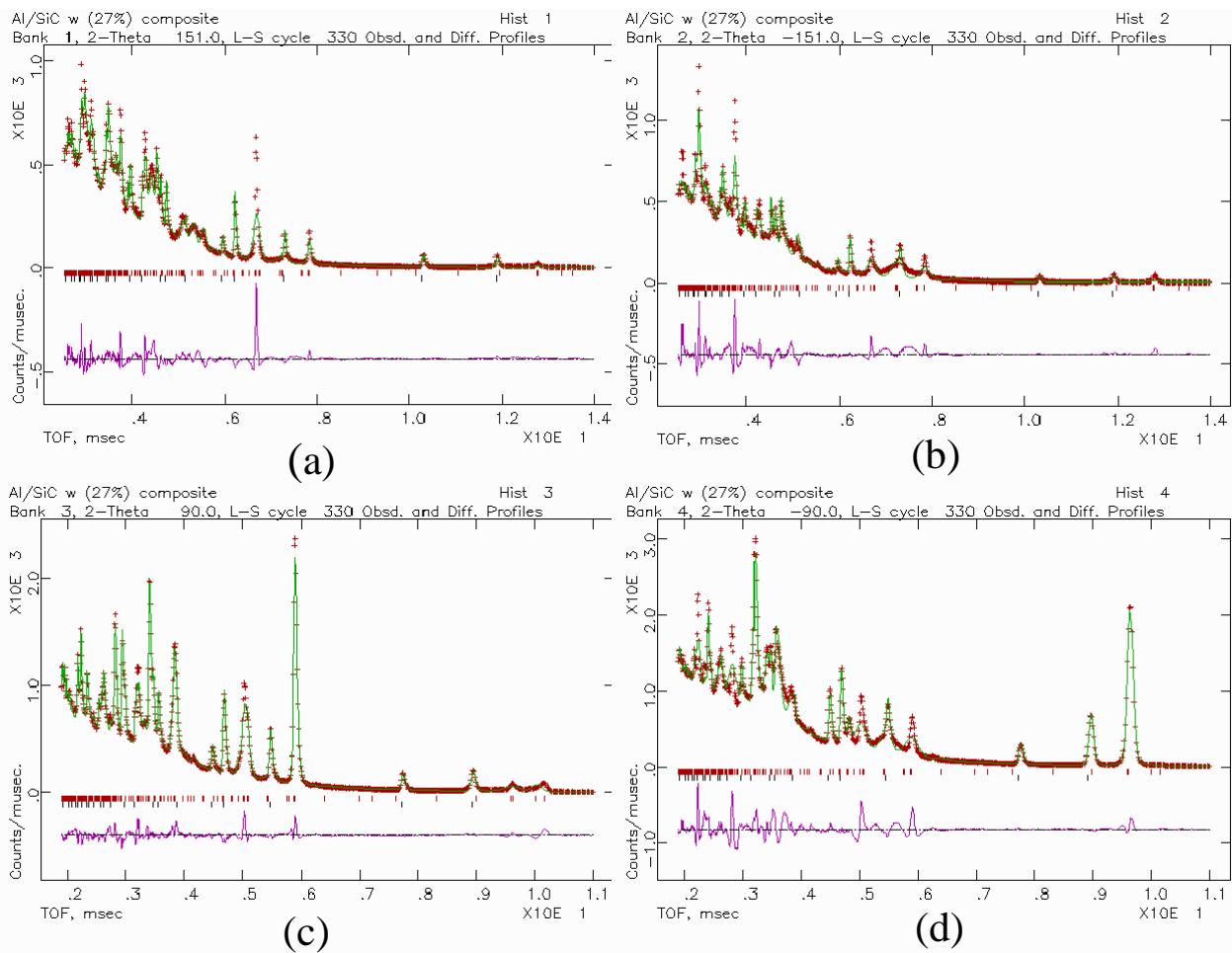
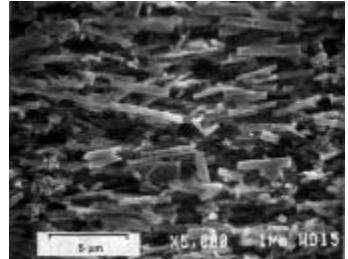
- Lattice parameters held constant at a_0 :

$$\langle e \rangle \equiv 0 = e'_{11} + e'_{22} + e'_{33}$$

$$\epsilon_{h,i} \Rightarrow e^H + e'_{kl}$$

LANSCE (LANL) Measurements

Al (6061)/SiC_w (hexagonal) — extrusions

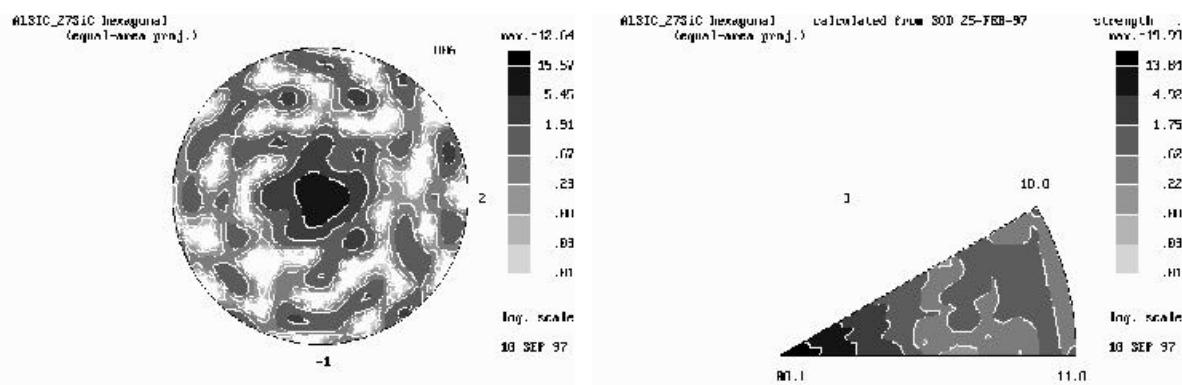
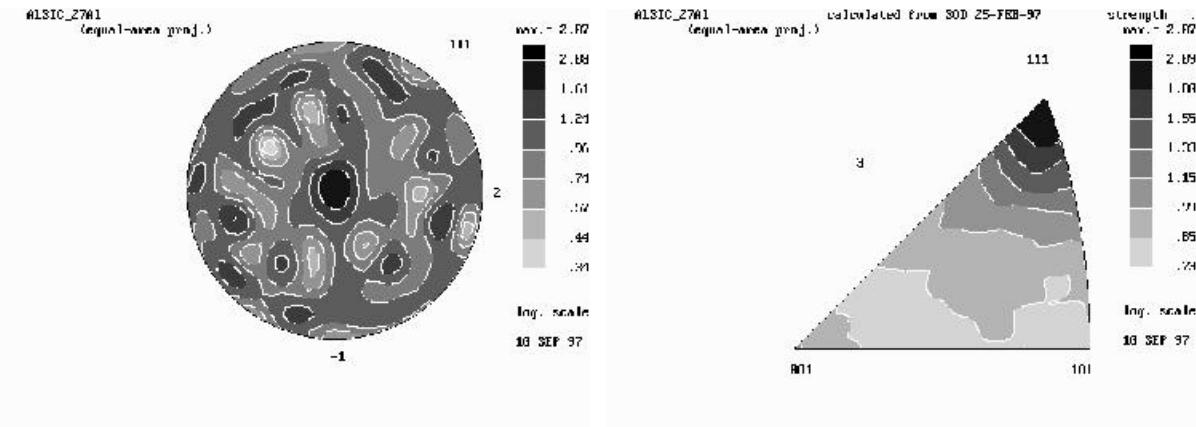


Complete Strain Tensor Al/SiC_w Composite

Strain (10^{-3})	Al	SiC
e_{11}	0.10(5)	-0.43(5)
e_{22}	0.13(5)	-0.33(4)
e_{33}	2.03(5)	0.64(7)
e_{12}	-0.13(4)	-0.10(4)
e_{13}	0.01(5)	0.17(6)
e_{23}	0.01(5)	0.02(6)

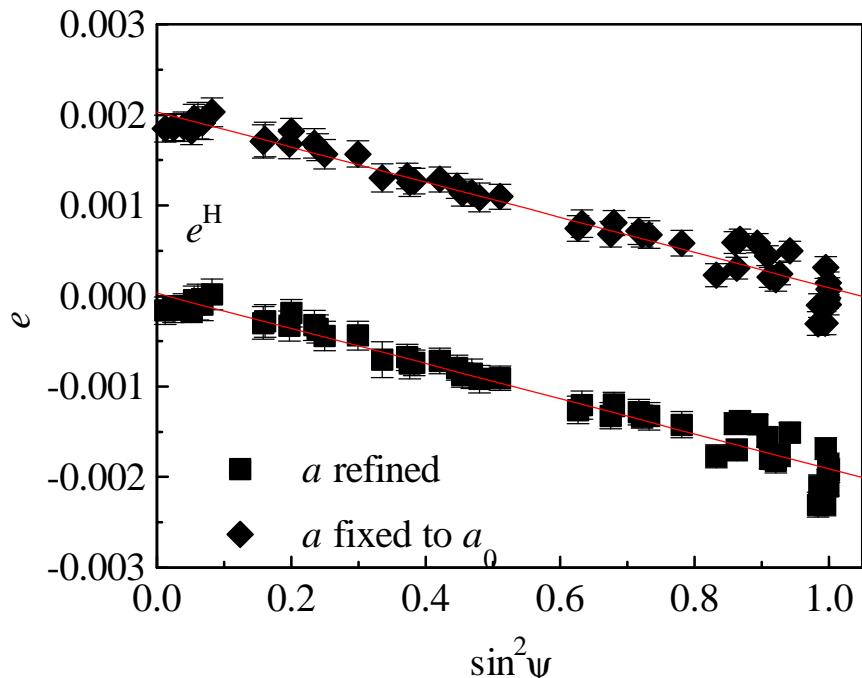
Pole Figures

W_{lmn} \longrightarrow Q_{lm} \longrightarrow Pole Figures

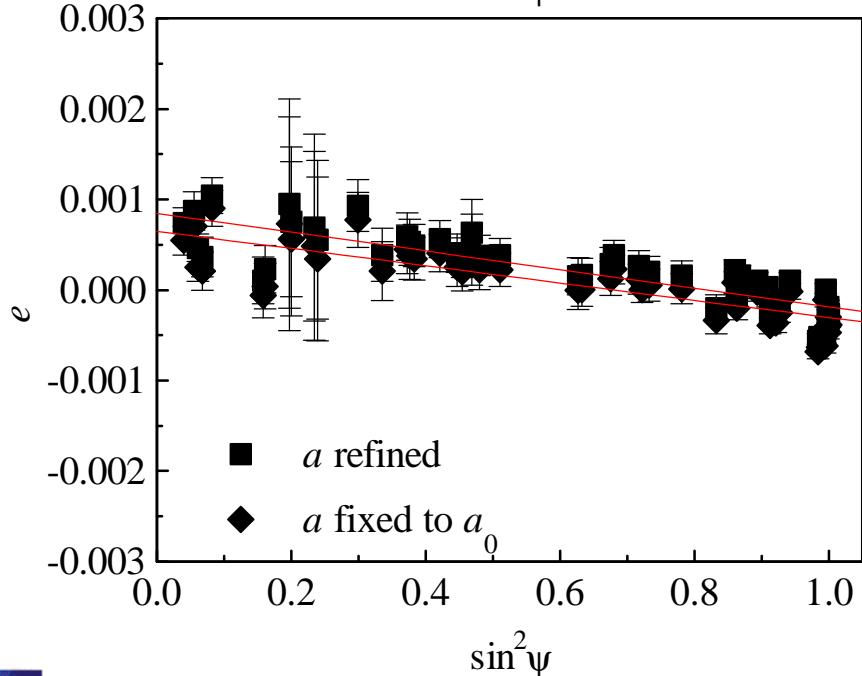


$$e(\psi) = e^H + e'_{33} + \left(\frac{e'_{11} + e'_{22}}{2} - e'_{33} \right) \sin^2 \psi$$

$\sin^2\psi$ plots



Al



SiC

Comparison of results

Al

Strain (10 ⁻³)	Linear Fit	Complete Tensor
e^H	2.00(8)	2.01(10)
e_{11}'	-1.91(10)	-1.91(6)
e_{22}'		-1.86(5)
e_{33}'	0.03(4)	0.02(4)

SiC

Strain (10 ⁻³)	Linear Fit	Complete Tensor
e^H	-0.19(14)	-0.14(11)
e_{11}'	-0.19(8)	-0.31(5)
e_{22}'		-0.22(4)
e_{33}'	0.84(7)	0.83(7)

Calculation of Stresses

- Isotropic:

$$\sigma_{ij} = \frac{1}{S_2/2} \left(e_{ij} - \delta_{ij} \frac{S_1}{S_2/2 + 3S_1} e_{kk} \right)$$

- Anisotropic:

$$\langle S_{ijkl} \rangle = T_{ijklmnp} S_{mnp}$$

$$T_{ijklmnp} = f(W_{lmn}) ! \text{ crystal \& specimen symmetry}$$

Stress

ISOTROPIC

ANISOTROPIC

Al (total)

$$\begin{bmatrix} 135(6) & -5(2) & 7(3) \\ \cdot & 133(7) & -9(3) \\ \cdot & \cdot & 231(6) \end{bmatrix}$$

$$\begin{bmatrix} 136(?) & -5(?) & 18(?) \\ \cdot & 135(?) & -26(?) \\ \cdot & \cdot & 244(?) \end{bmatrix}$$

SiC (deviatoric)

$$\begin{bmatrix} -113(17) & -21(12) & 64(18) \\ \cdot & -117(20) & -118(21) \\ \cdot & \cdot & 195(33) \end{bmatrix}$$

$$\begin{bmatrix} -290(?) & -14(?) & 57(?) \\ \cdot & -293(?) & -106(?) \\ \cdot & \cdot & 240(?) \end{bmatrix}$$

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Future ?

